# NSN 5962-01-180-5311

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View Online at https://aerobasegroup.com/nsn/5962-01-180-5311

view Online at https://aeiobasegioup.com/nsii/3902-01-180-5311
Overall Length:
0.840 inches
Overall Height:
0.400 inches
Body Length:
0.840 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
794.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1260-01-165-3961 mast mounted sight
Features Provided:
W/active pull-up and 3-state output and high impedance and bipolar and schottky and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
D-2 mil-m-38510
Current Rating Per Characteristic:
140.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
40.00 nanoseconds propagation delay time, high to low level output and 40.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom
Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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## AeroBase Group

### Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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